

isc Silicon NPN Power Transistor

DESCRIPTION

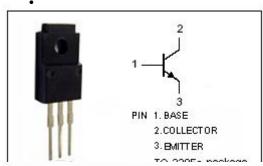
- · Collector-Emilter Breakdown Voltage-
- : V_{(BR)CEO}= 800V(Min.)
- Wide Area of Safe Operation
- · High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

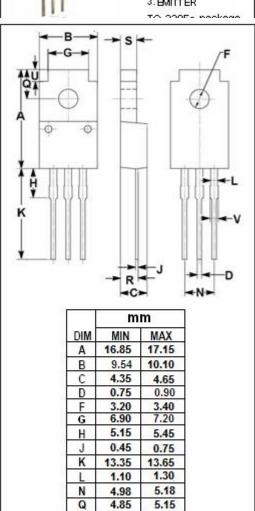
APPLICATIONS

• Designed for high speed switching applications.

ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	900	V	
Vceo	Collector-Emitter Voltage	V		
V_{EBO}	Emitter-Base Voltage 7		V	
lc	Collector Current-Continuous 2		Α	
Ісм	Collector Current-Peak	4	А	
I _B	Base Current-Continuous	1	Α	
P _C	Collector Power Dissipation @T _a =25℃	2	W	
	Collector Power Dissipation @T _C =25°C	40	vv	
T _j	Junction Temperature	150	$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	${\mathbb C}$	





R

S

U

2.55

2.70

1.75

1.30

3.25 2.90

2.05



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2SC3743

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

1c-25 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	800			V			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.8A; I _B = 0.16A			0.6	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.8A; I _B = 0.16A			1.2	V			
I _{CBO}	Collector Cutoff Current	V _{CB} = 900V; I _E = 0			50	μ A			
І _{ЕВО}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			50	μ A			
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	6						
h _{FE-2}	DC Current Gain	I _C = 0.8A; V _{CE} = 5V	6						
Switching Times									
t _{on}	Turn-on Time				1.0	μS			
ts	Storage Time	I _C = 0.8A; I _{B1} = 0.16A;I _{B2} = -0.32A; V _{CC} = 250V			4.0	μS			
t _f	Fall Time				1.0	μs			

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